

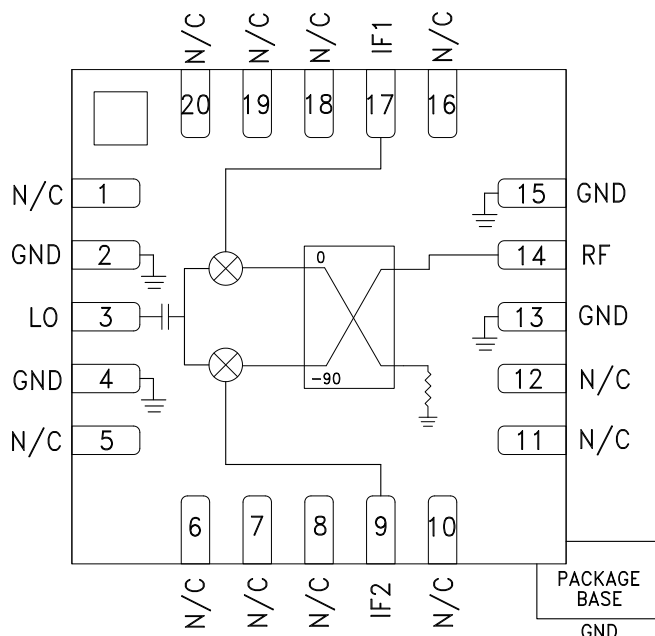


Typical Applications

The HMC1056LP4BE is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

Functional Diagram



Features

- Wide IF Bandwidth: DC - 4 GHz
- Image Rejection: 25 dBc
- LO to RF isolation: 40 dB
- High Input IP3: 18 dBm
- 20 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC1056LP4BE is a compact I/Q MMIC mixer in a leadless "Pb free" SMT package, which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs Schottky diode process. A low frequency quadrature hybrid was used to produce a 100MHz LSB IF output. This product is a much smaller alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC1056LP4BE eliminates the need for wire bonding and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ\text{C}$, IF = 100 MHz, LSB, LO = +10 dBm ^[1]

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF/LO		8 - 10		10 - 12			GHz
Frequency Range, IF		DC - 4		DC - 4			GHz
Conversion Loss		8	11		8	11	dB
Image Rejection	18	25		12	18		dBc
LO to RF isolation	33	40		33	40		dB
LO to IF isolation		35			40		dB
IP3 (input)		18			17		dBm
Amplitude Balance ^[2]		+0.5			+1.5		dB
Phase Balance ^[2]		+2.5			-2.5		Deg

[1] Unless otherwise noted all measurements performed as downconverter.

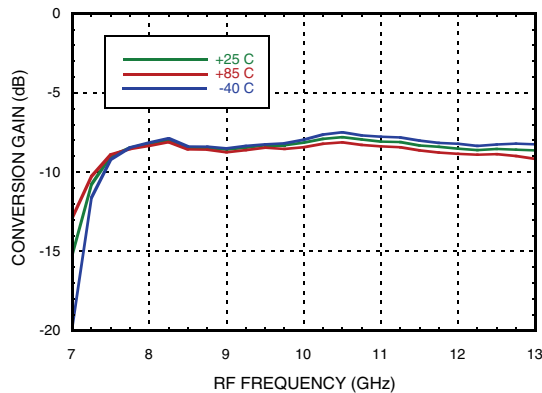
[2] Data taken without external 90° hybrid.



**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

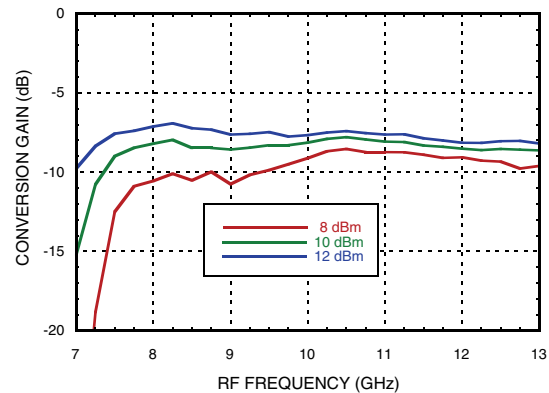


Image Rejection, LSB vs. Temperature

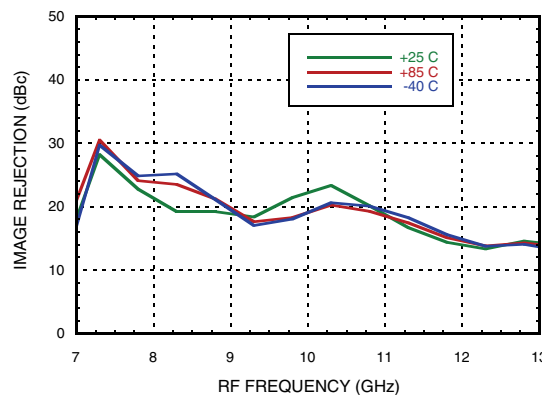
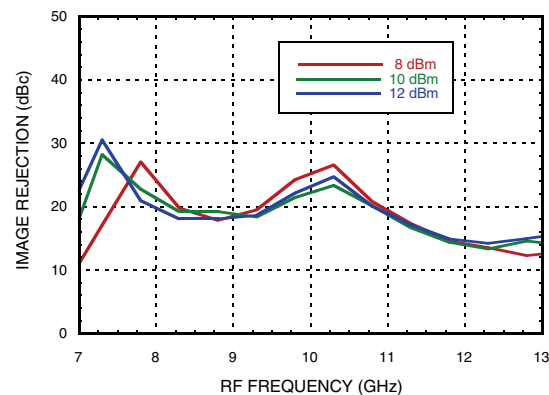
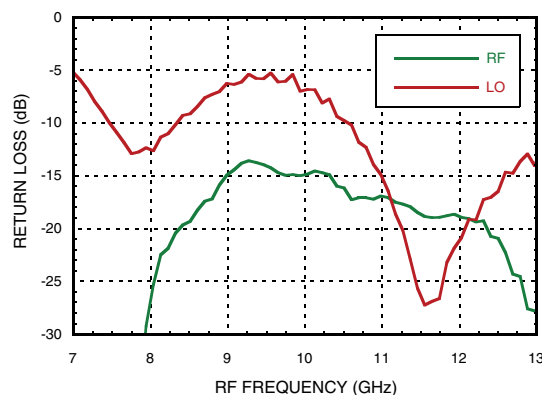


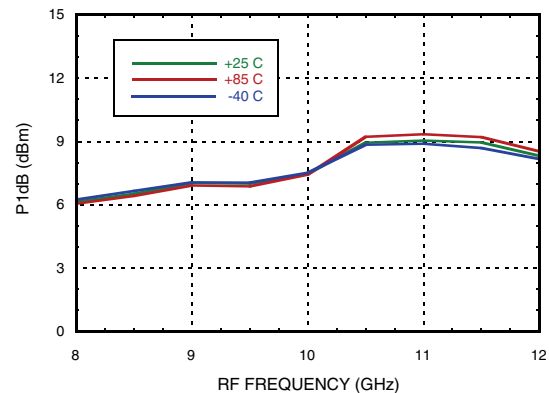
Image Rejection, LSB vs. LO Drive



Return Loss



Input P1dB, LSB vs. Temperature



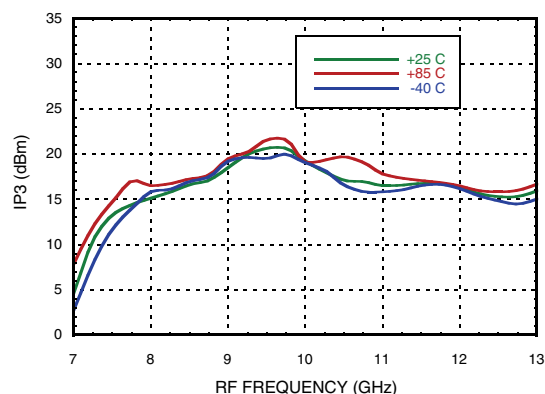
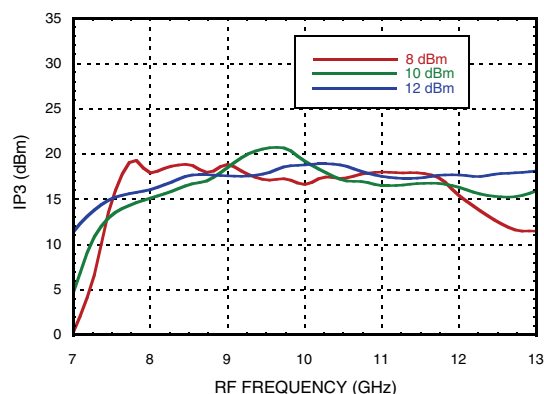
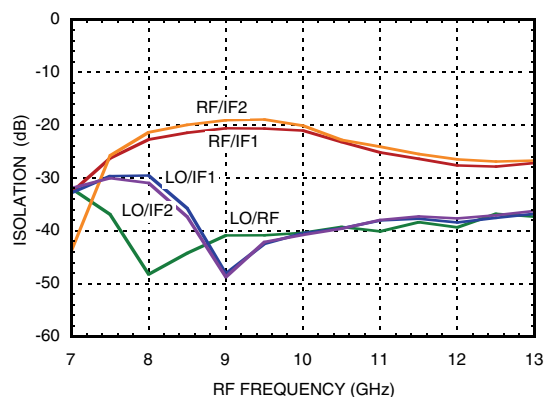
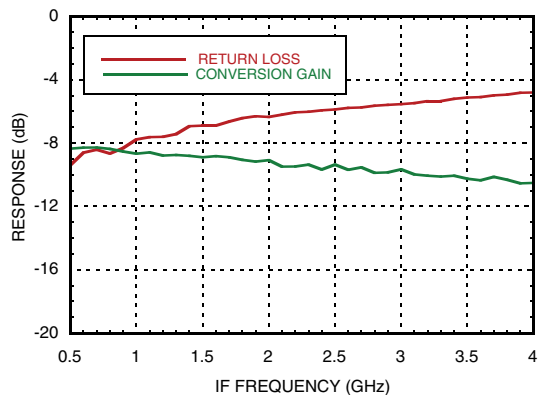
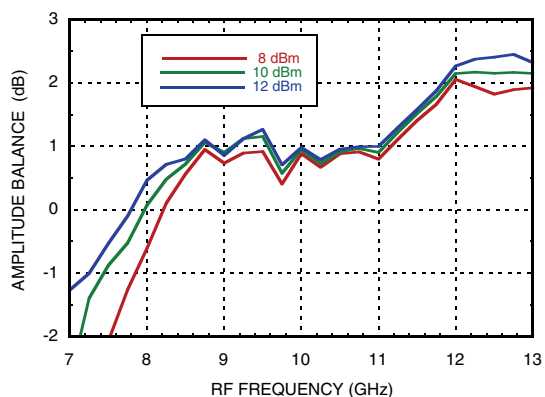
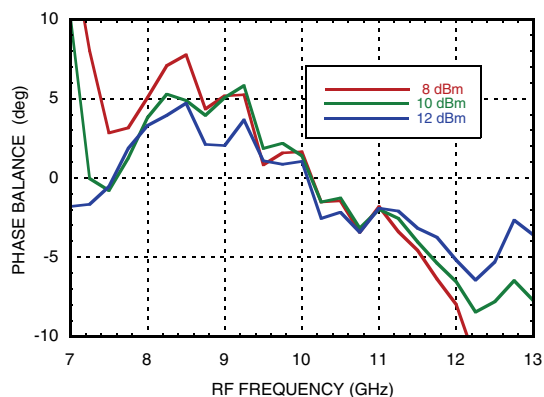
[1] Data taken without external IF 90° hybrid

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**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

Input IP3, LSB vs. Temperature

Input IP3, LSB vs. LO Drive

Isolations

IF Bandwidth*

Amplitude Balance, LSB vs. LO Drive

Phase Balance, LSB vs. LO Drive


* Conversion gain data taken with external IF hybrid.

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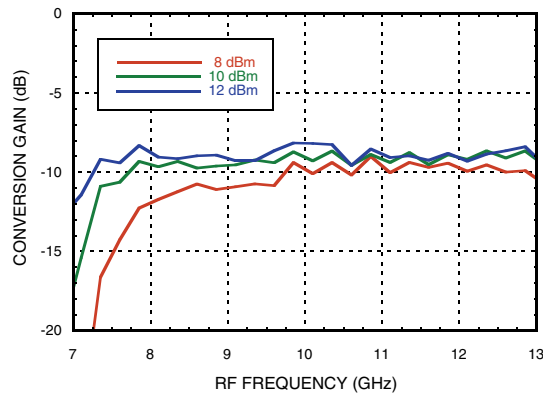
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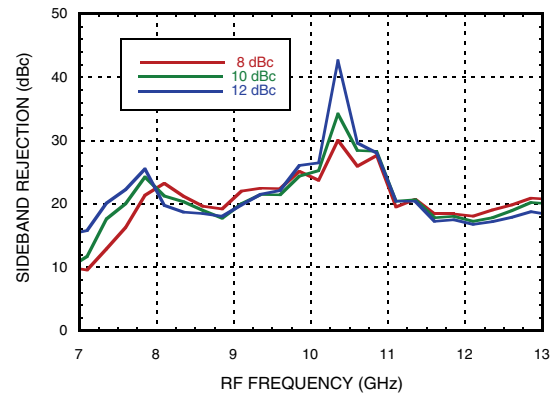
**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

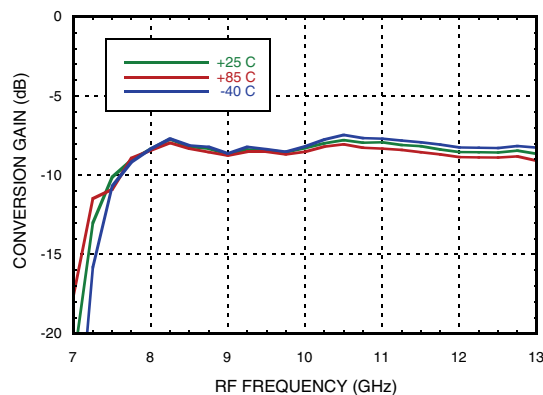
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

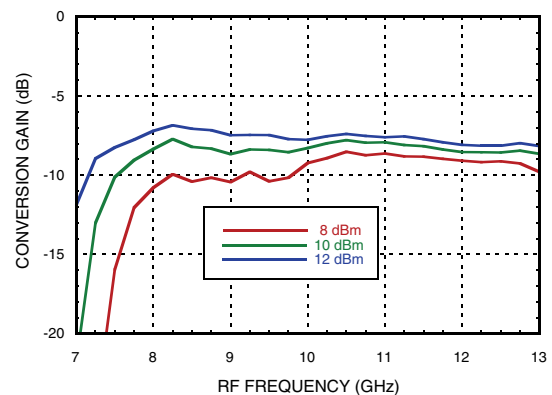


Image Rejection, USB vs. Temperature

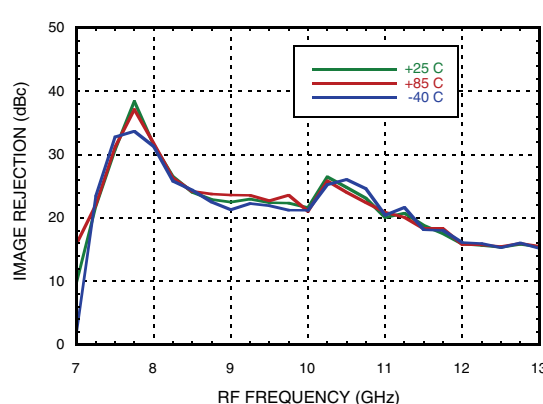
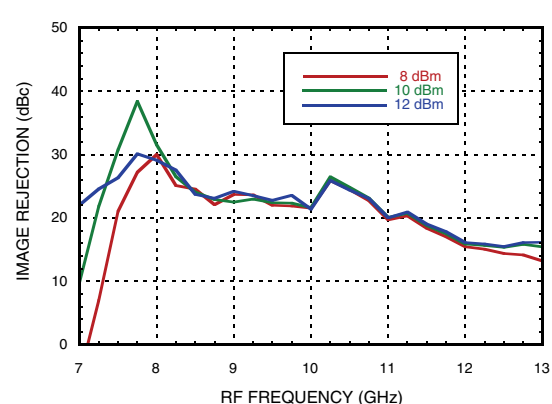
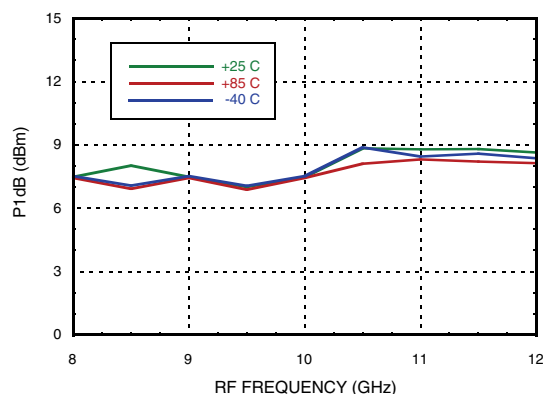
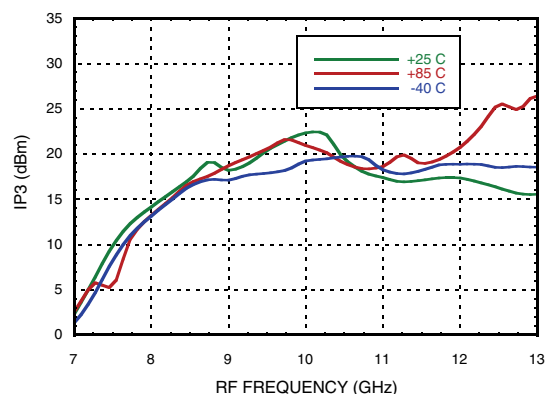
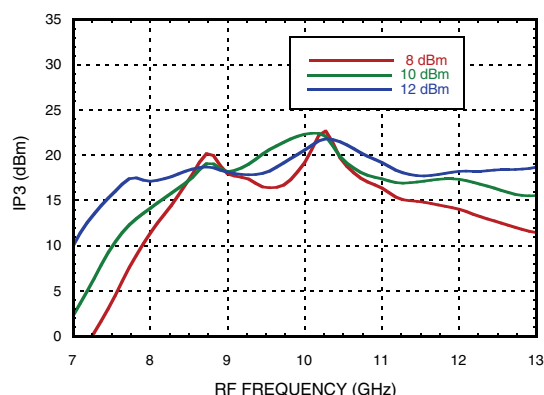
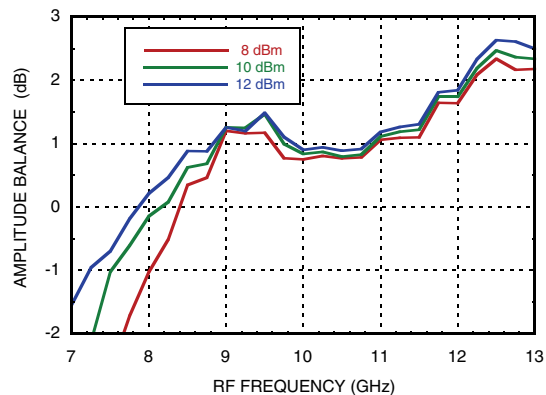
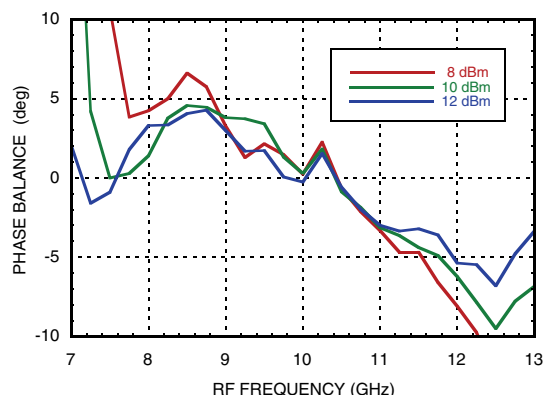
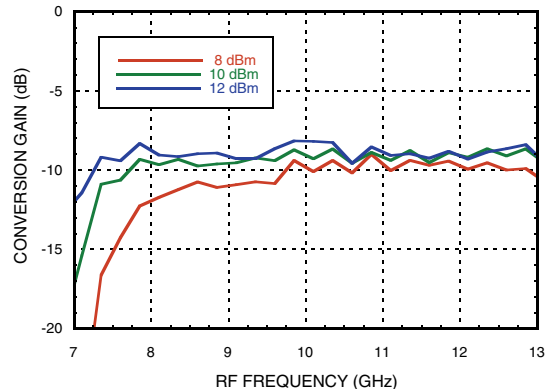


Image Rejection, USB vs. LO Drive



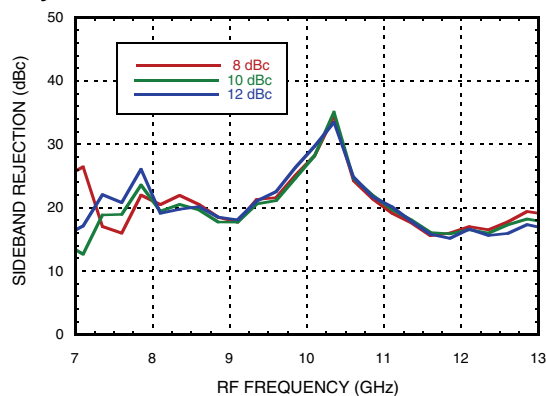

**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

Input P1dB, USB vs. Temperature

Input IP3, USB vs. Temperature

Input IP3, USB vs. LO Drive

Amplitude Balance, USB vs. LO Drive

Phase Balance, USB vs. LO Drive

**Upconverter Performance, Conversion
Gain, USB vs. LO Drive**


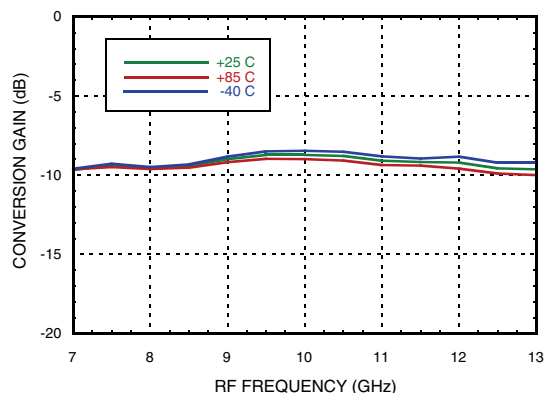
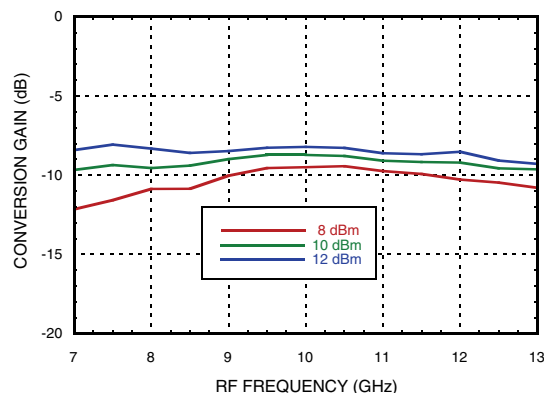
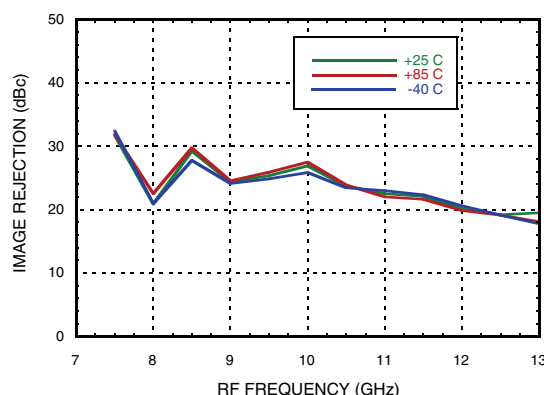
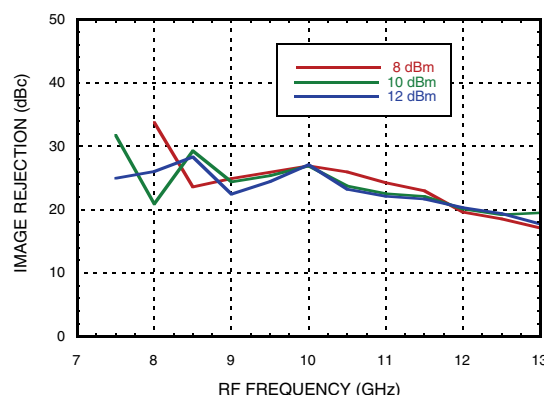
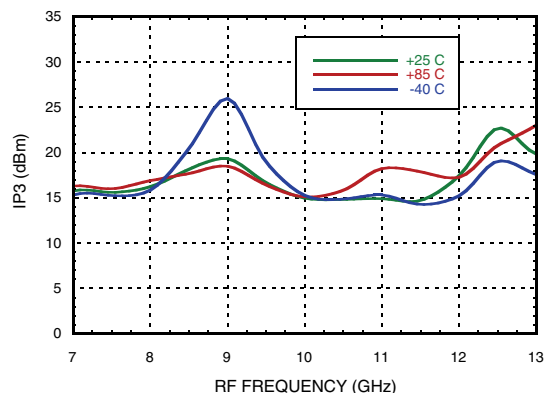
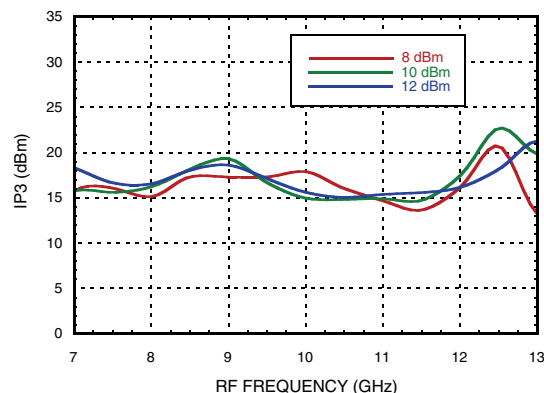
Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 100 MHz

**Upconverter Performance, Sideband
Rejection, USB vs. LO Drive,**




**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

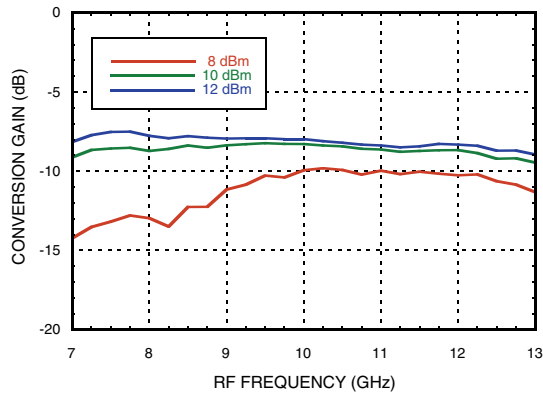
Conversion Gain, LSB vs. Temperature

Conversion Gain, LSB vs. LO Drive

Image Rejection, LSB vs. Temperature

Image Rejection, LSB vs. LO Drive

Input IP3, LSB vs. Temperature

Input IP3, LSB vs. LO Drive




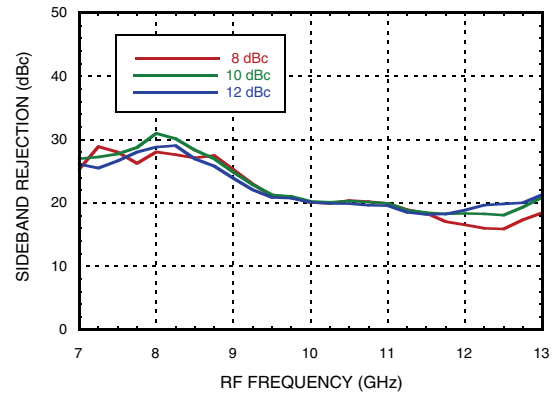
**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

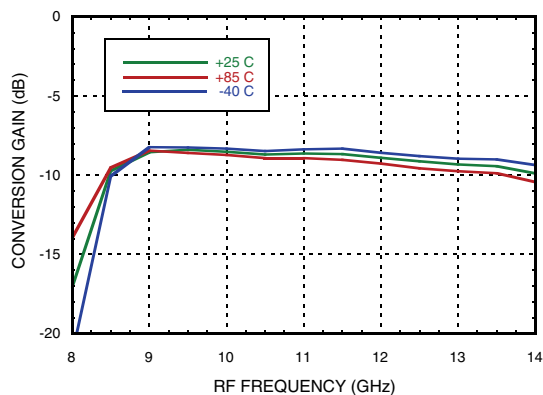
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

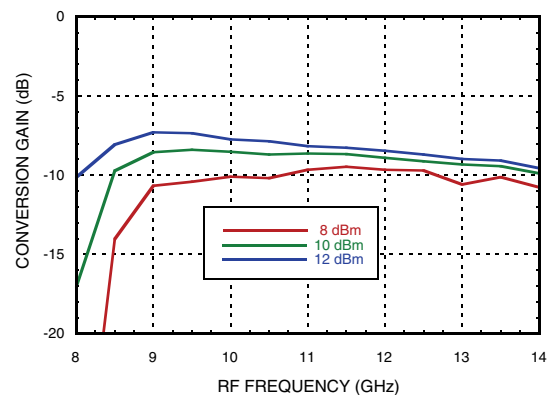


Image Rejection, USB vs. Temperature

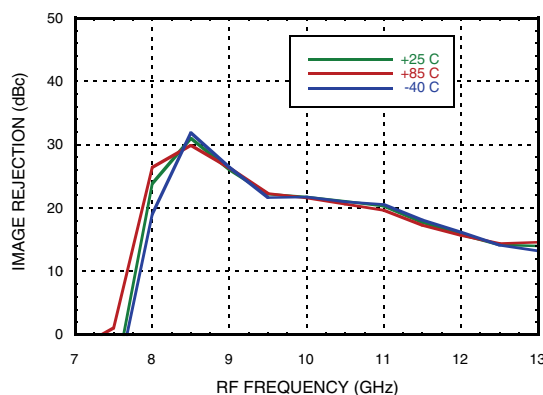
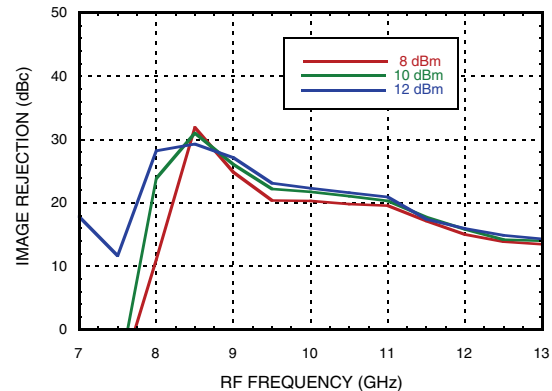


Image Rejection, USB vs. LO Drive





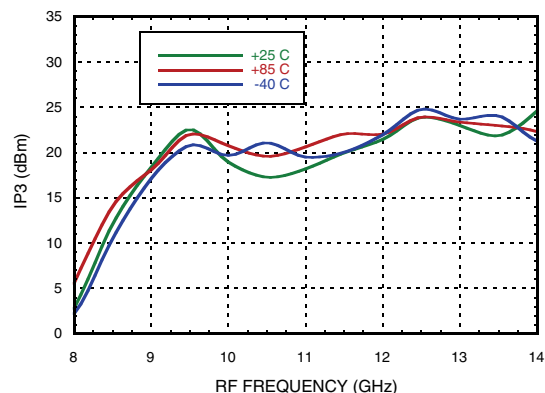
v00.1012

HMC1056LP4BE

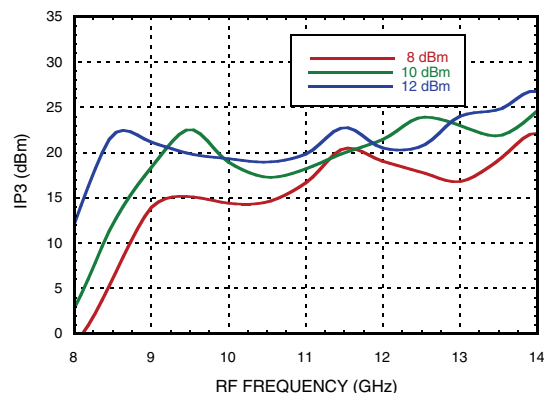
GaAs MMIC I/Q Mixer
8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

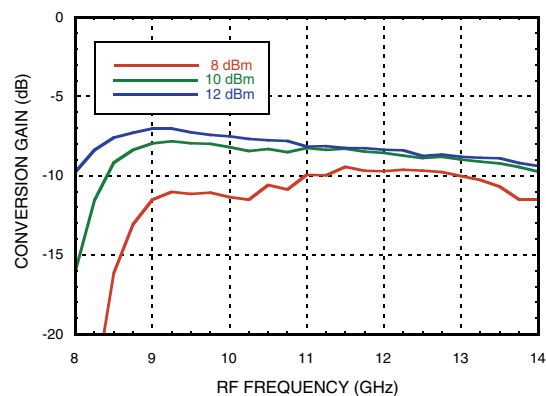
Input IP3, USB vs. Temperature



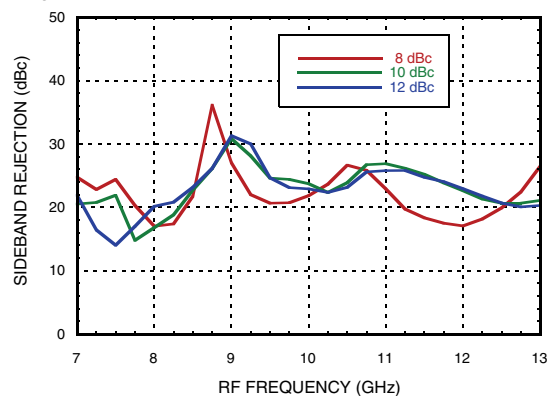
Input IP3, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



Upconverter Performance, Sideband Rejection, USB vs. LO Drive

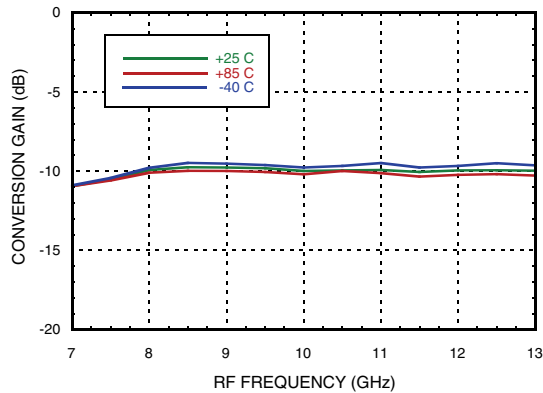




**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

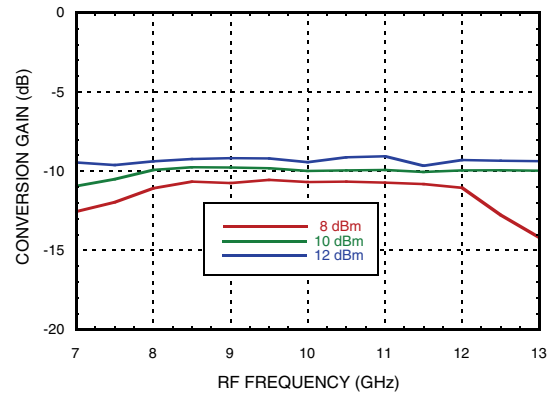


Image Rejection, LSB vs. Temperature

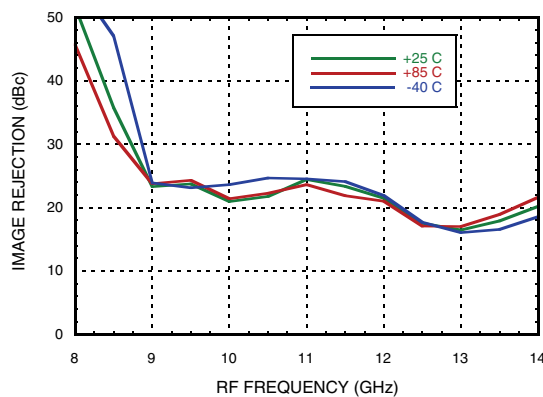
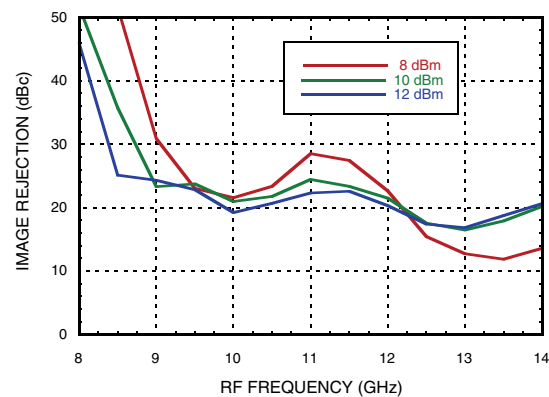
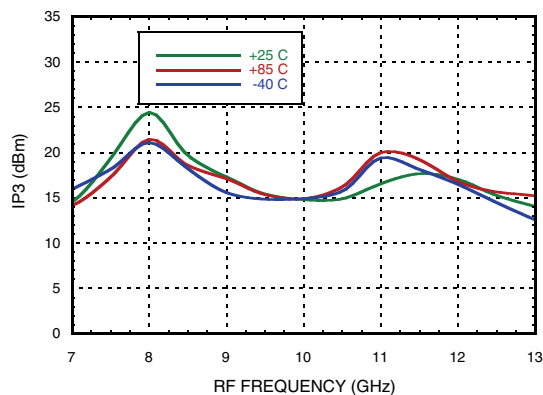


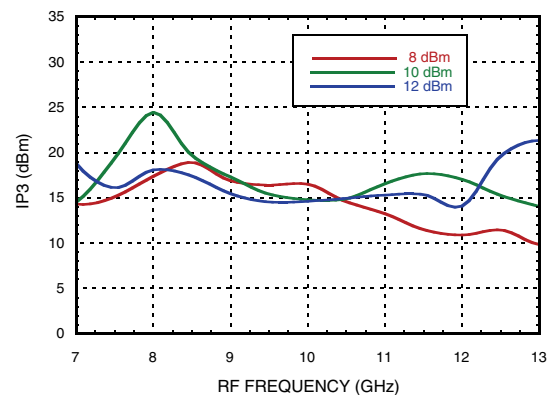
Image Rejection, LSB vs. LO Drive



Input IP3, LSB vs. Temperature



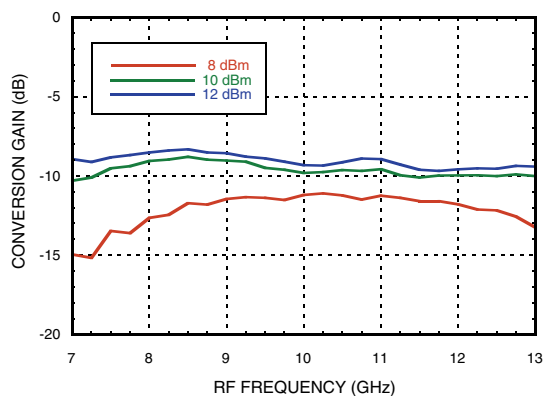
Input IP3, LSB vs. LO Drive



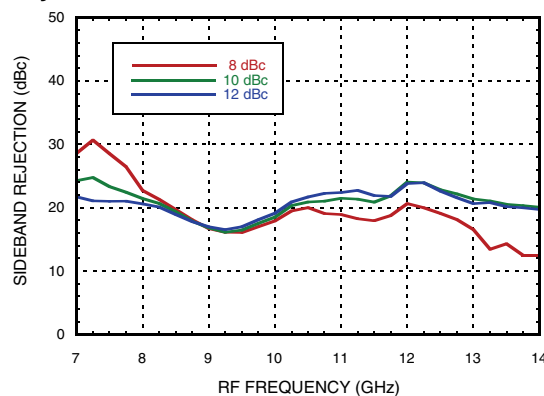

**GaAs MMIC I/Q Mixer
8 - 12 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

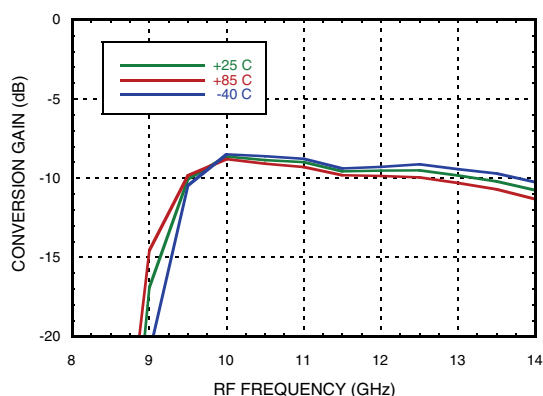
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

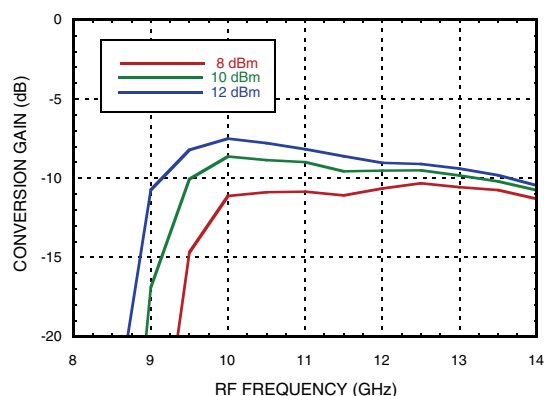


Image Rejection, USB vs. Temperature

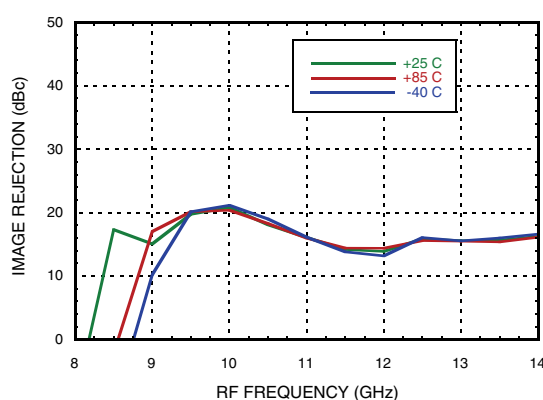
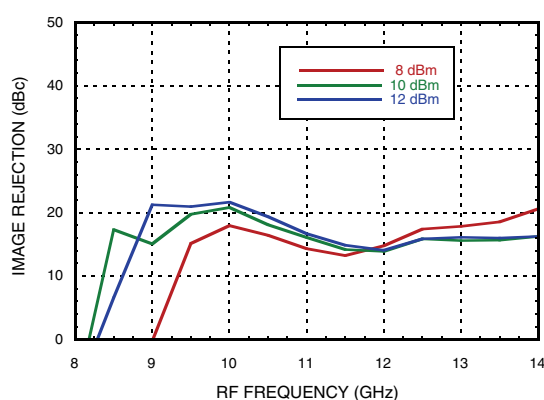
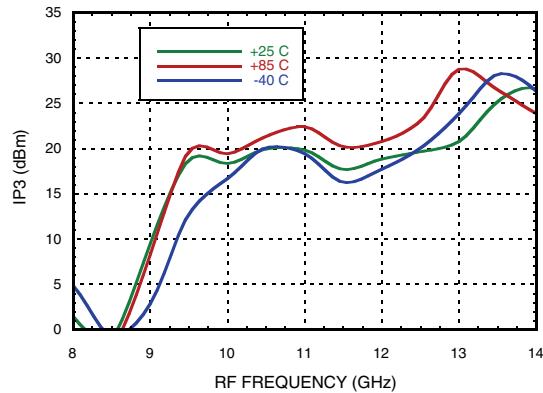
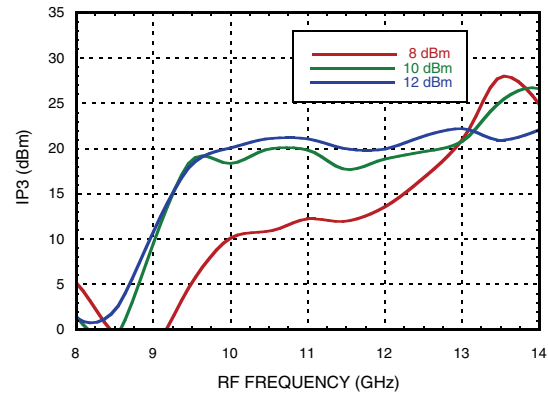
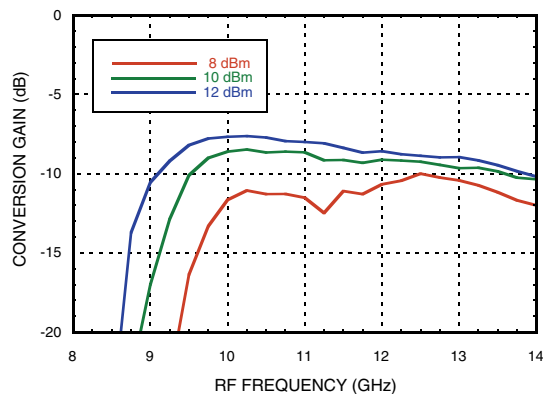
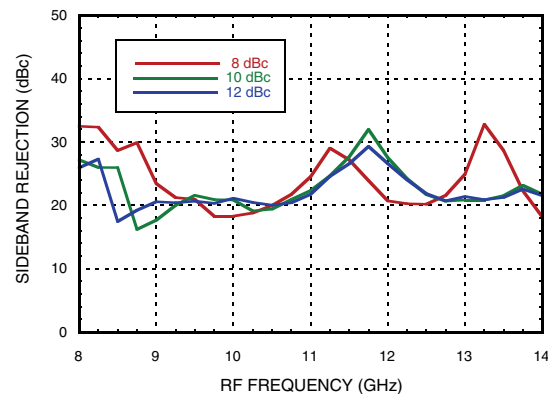


Image Rejection, USB vs. LO Drive



Input IP3, USB vs. Temperature

Input IP3, USB vs. LO Drive

Upconverter Performance, Conversion Gain, USB vs. LO Drive

Upconverter Performance, Sideband Rejection, USB vs. LO Drive,

Harmonics of LO

LO Freq. (GHz)	nLO Spur at RF Port			
	1	2	3	4
7	41.3	37.6	74.4	74.2
8	36.3	36.3	52	82.1
9	37.2	52.9	63.6	81.4
10	36.8	56.4	65.5	100.4
11	37.3	59.8	68.9	68.8
12	37.4	56.2	65.3	78.9
13	38.1	56.4	69.6	x

LO = + 10 dBm
Values in dBc below LO level measured at RF Port.

MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	xx	8	38	48	60
1	8	0	28	43	60
2	64	50	56	48	67
3	94	78	67	64	78
4	x	x	x	x	x

RF = 10 GHz @ -10 dBm
LO = 10.1 GHz @ +10 dBm
Data taken without IF hybrid
All values in dBc below IF power level



IF Input (At LO = 10 dBm and RF = -10 dBm)	+15.5 dBm
RF Input (At 10 dBm LO power)	+16 dBm
LO Input (At -10 dBm RF power)	+17 dBm
Channel Temperature	175 °C
Continuous P _{diss} (T = 85°C) (derate 8.9 mW/°C above 85°C)	800 mW
Thermal Resistance (channel to ground paddle)	112 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0, Passed 150V



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

The drawing consists of three views of a 16-pin DIP package:

- Top View:** Shows the package body with a width of 0.161 inches [4.10 mm] and a length of 0.153 inches [3.90 mm]. The pin pitch is 0.026 inches [0.65 mm]. The package is marked with "H1056" and "XXXX". The distance from the top edge to the center of the package is 0.153 inches [3.90 mm]. The distance from the bottom edge to the center is 0.161 inches [3.90 mm]. The distance from the left edge to the center is 0.153 inches [3.90 mm]. The distance from the right edge to the center is 0.161 inches [3.90 mm].
- Side View:** Shows the package height of 0.081 inches [2.06 mm]. The distance from the top edge to the center of the package is 0.076 inches [1.94 mm]. The distance from the bottom edge to the center is 0.081 inches [2.06 mm].
- End View:** Shows the package width of 0.091 inches [2.30 mm]. The distance from the top edge to the center of the package is 0.079 inches [2.00 mm]. The distance from the bottom edge to the center is 0.091 inches [2.30 mm]. The package is marked with "H1056" and "XXXX". The distance from the top edge to the center of the package is 0.079 inches [2.00 mm]. The distance from the bottom edge to the center is 0.091 inches [2.30 mm].

Additional dimensions and features include:

- Pin 1:** Located at the top right of the package.
- Pin 20:** Located at the top left of the package.
- Exposed Ground Paddle:** Located on the right side of the package.
- Seating Plane:** Indicated by a triangle on the bottom edge.
- Lot Number:** Indicated by an arrow pointing to the "XXXX" marking.
- Dimensions:** All dimensions are given in inches and millimeters.

NOTES:

1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY.
3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.

Part Number	Package Body Material	Lead Finish	MSL Rating ^[2]	Package Marking ^[1]
HMC1056LP4BE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	H1056 XXXX

[1] 4-Digit lot number XXXX

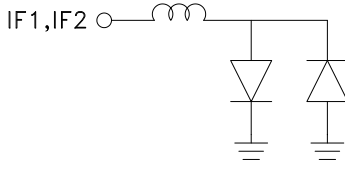
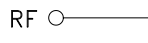
[2] Max peak reflow temperature of 260 °C

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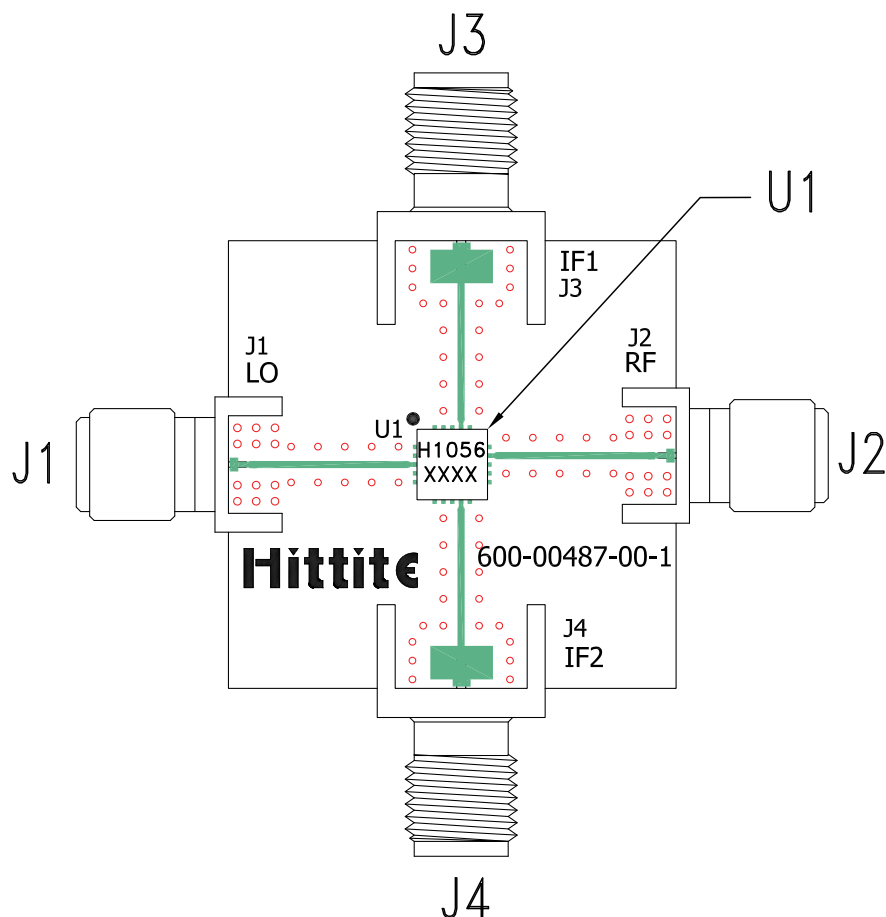
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5-8, 10-12, 16, 18-20	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2, 4, 13, 15	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
3	LO	This pin is AC coupled and matched to 50 Ohms .	
9	IF2	Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should be used. For operation to DC this pin must not source/sink more than 3mA of current or part non function and possible part failure will result.	
17	IF1		
14	RF	This pin is matched to 50 Ohms.	

Evaluation PCB



List of Materials for Evaluation PCB EVAL01-HMC1056LP4B^[1]

Item	Description
J1, J2	PCB Mount SMA RF Connector, SRI
J3 - J4	PCB Mount SMA Connector, Johnson
U1	HMC1056LP4BE
PCB [2]	600-00487-00-1 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



v00.1012

HMC1056LP4BE

GaAs MMIC I/Q Mixer
8 - 12 GHz

Notes:

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